

# ISA1530AC1

FOR LOW FREQUENCY AMPLIFY APPLICATION  
SILICON PNP EPITAXIAL TYPE

## DESCRIPTION

ISA1530AC1 is a mini package resin sealed silicon PNP epitaxial transistor, It is designed for low frequency voltage application.

## FEATURE

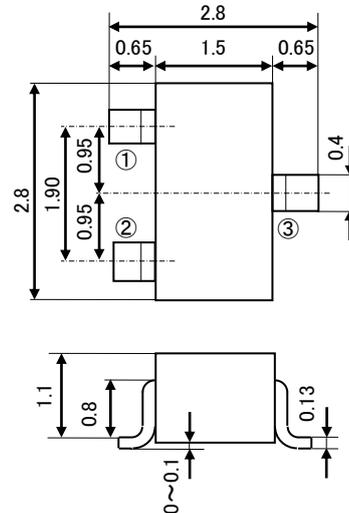
- Small collector to emitter saturation voltage.  
 $V_{CE(sat)} = -0.3V \text{ max (@} I_C = -100mA / I_B = -10mA \text{)}$
- Excellent linearity of DC forward current gain.
- Super mini package for easy mounting.

## APPLICATION

For small type machine low frequency voltage amplify application

## OUTLINE DRAWING

Unit: mm



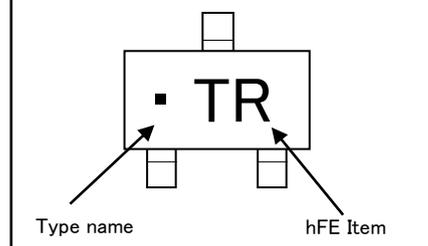
## TERMINAL CONNECTER

- ①: BASE JEITA:SC-59
- ②: EMITTER JEDEC: Similar to TO-236
- ③: COLLECTOR

## MAXIMUM RATINGS ( $T_a = 25^\circ\text{C}$ )

Parameter	Symbol	Ratings	Unit
Collector to Base voltage	$V_{CBO}$	-60	V
Emitter to Base voltage	$V_{EBO}$	-6	V
Collector to Emitter voltage	$V_{CEO}$	-50	V
Collector current	$I_C$	-150	mA
Collector dissipation	$P_C$	200	mW
Junction temperature	$T_J$	+150	$^\circ\text{C}$
Storage temperature	$T_{stg}$	-55 ~ +150	$^\circ\text{C}$

## MARKING



## ELECTRICAL CHARACTERISTICS ( $T_a = 25^\circ\text{C}$ )

Parameter	Symbol	Test conditions	Limits			Unit
			Min	Typ	Max	
C to E breakdown voltage	$V_{(BR)CEO}$	$I_C = -100 \mu\text{A}, R_{BE} = \infty$	-50	-	-	V
Collector cut off current	$I_{CBO}$	$V_{CB} = -60V, I_E = 0mA$	-	-	-0.1	$\mu\text{A}$
Emitter cut off current	$I_{EBO}$	$V_{EB} = -4V, I_C = 0mA$	-	-	-0.1	$\mu\text{A}$
DC forward current gain ※	$h_{FE}$	$V_{CE} = -6V, I_C = -1mA$	120	-	560	-
DC forward current gain	$h_{FE}$	$V_{CE} = -6V, I_C = -0.1mA$	70	-	-	-
C to E Saturation voltage	$V_{CE(sat)}$	$I_C = -100mA, I_B = -10mA$	-	-	-0.3	V
Gain bandwidth product	$f_T$	$V_{CE} = -6V, I_E = 10mA$	-	200	-	MHz
Collector output capacitance	$C_{ob}$	$V_{CB} = -6V, I_E = 0, f = 1MHz$	-	4.0	-	pF
Noise figure	NF	$V_{CE} = -6V, I_E = 0.3mA, f = 100Hz, R_G = 10k \Omega$	-	-	20	dB

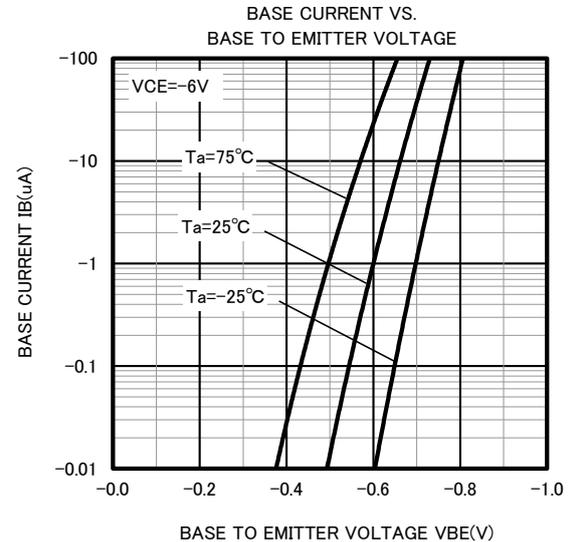
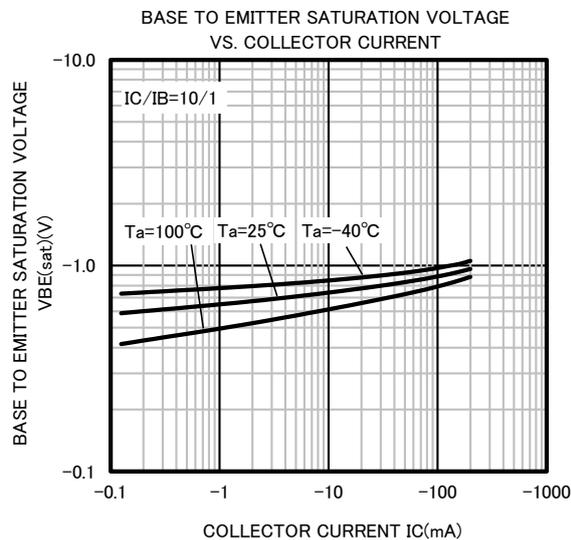
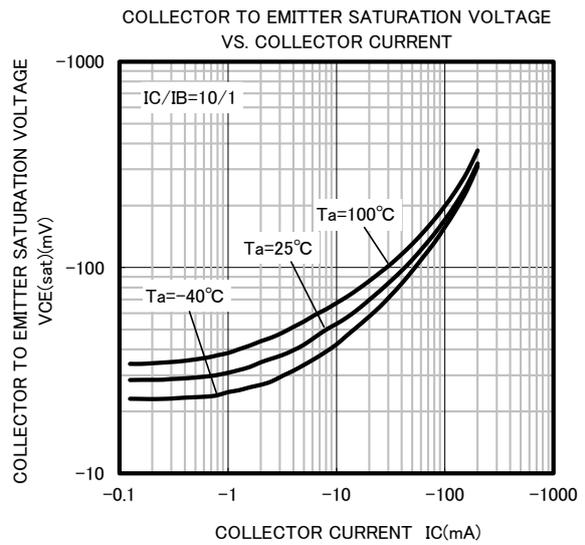
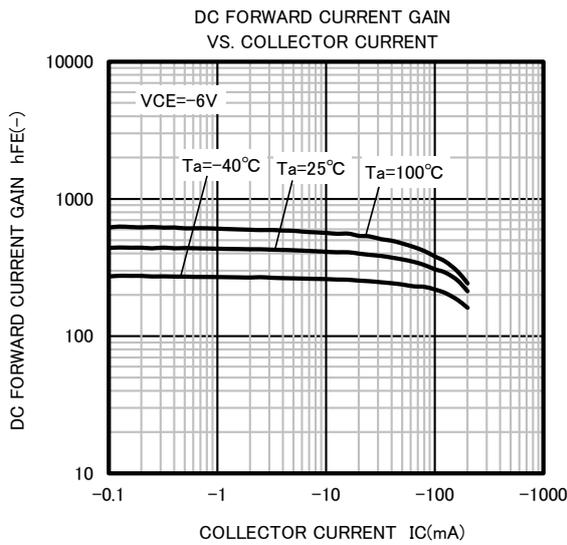
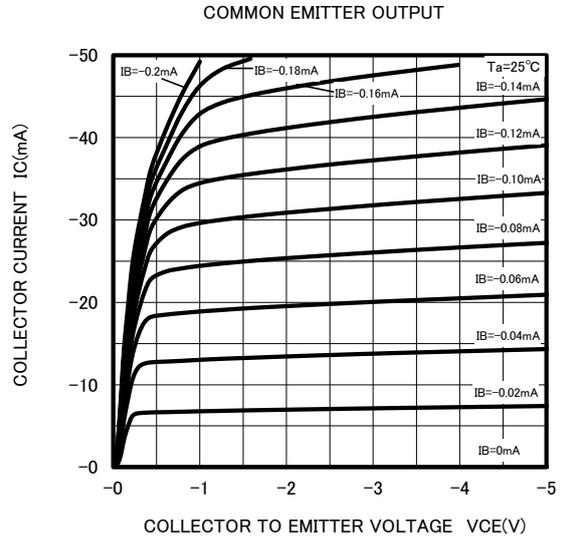
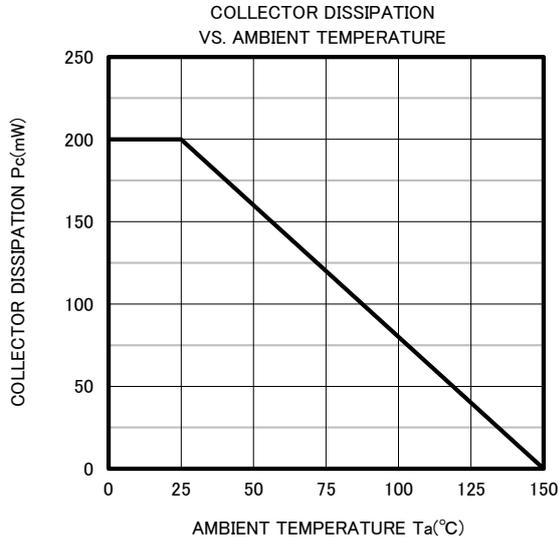
※) It shows hFE classification at right table.

Item	Q	R	S
hFE	120~270	180~390	270~560

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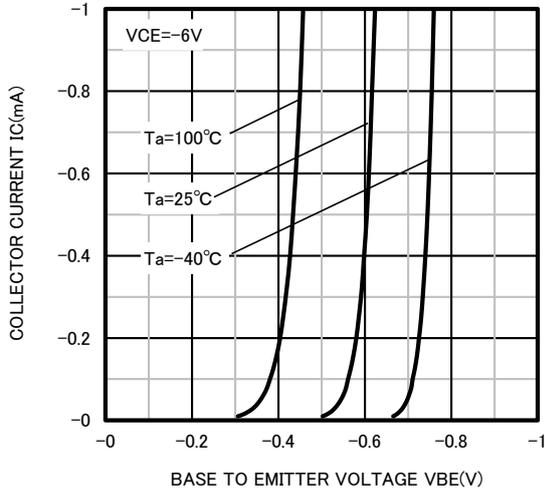
## TYPICAL CHARACTERISTICS



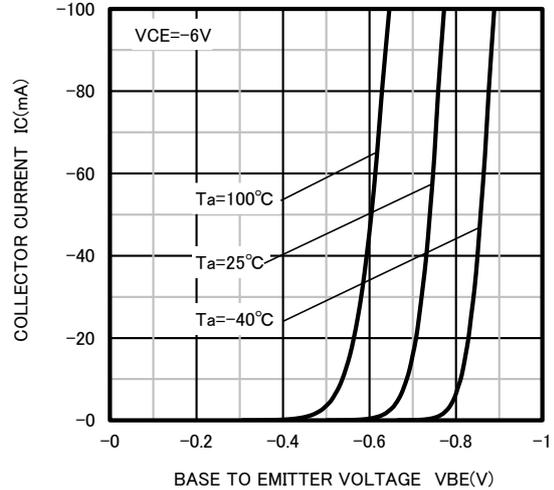
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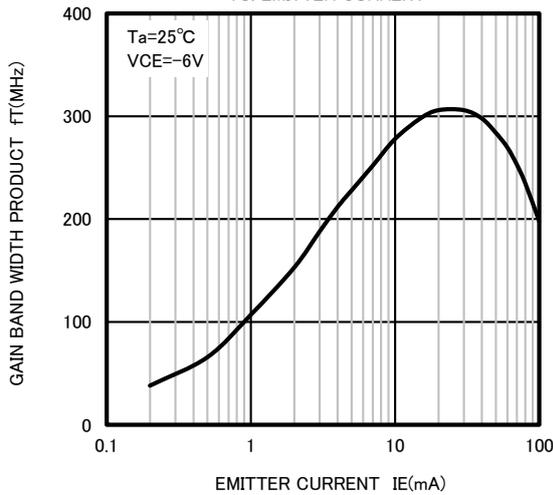
COMMON EMITTER TRANSFER



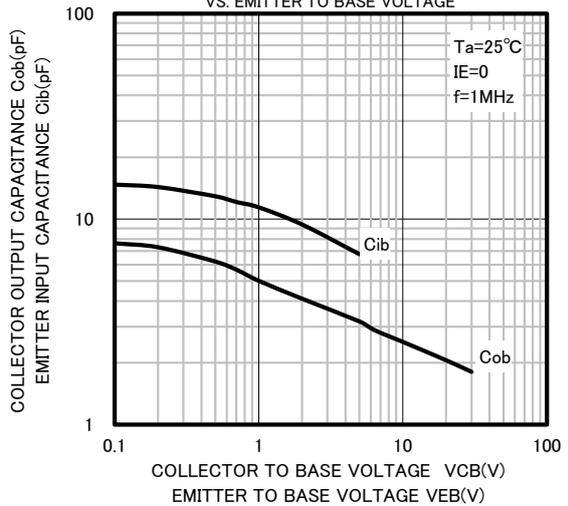
COMMON EMITTER TRANSFER



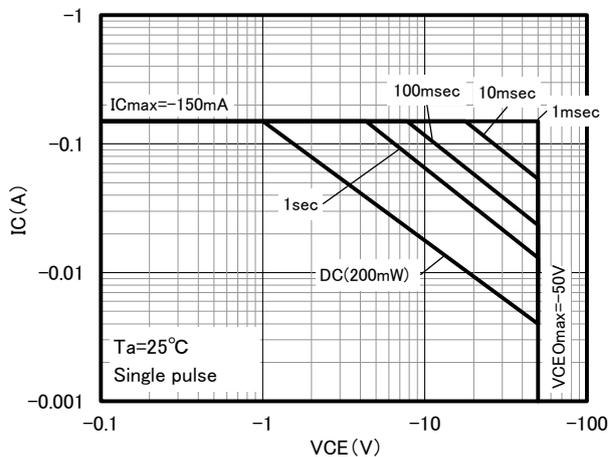
GAIN BAND WIDTH PRODUCT VS. EMITTER CURRENT



COLLECTOR OUTPUT CAPACITANCE VS. COLLECTOR TO BASE VOLTAGE  
EMITTER INPUT CAPACITANCE VS. EMITTER TO BASE VOLTAGE



ASO



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